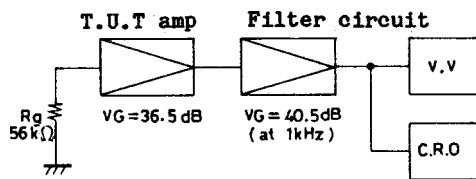


**Low Noise AF Amp Applications****Features**

- Adoption of FBET process.
- AF amp.
- Low-noise use.

**Noise Test Circuit**

( ) : 2SA1391

**Specifications****Absolute Maximum Ratings at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		(-)60	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)50	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)200	mA
Collector Current (Pulse)	$I_{CP}$		(-)400	mA
Collector Dissipation	$P_C$		400	mW
Junction Temperature	$T_J$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

**Electrical Characteristics at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = (-)40V, I_E = 0$			(-)0.1	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = (-)5V, I_C = 0$			(-)0.1	$\mu A$
DC Current Gain	$h_{FE1}$	$V_{CE} = (-)6V, I_C = (-)1mA$	100*		560*	
	$h_{FE2}$	$V_{CE} = (-)6V, I_C = (-)0.1mA$	70			
Gain-Bandwidth Product	$f_T$	$V_{CE} = (-)6V, I_C = (-)10mA$		250		MHz
				(200)		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)100mA, I_B = (-)10mA$			(-)0.3	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)100mA, I_B = (-)10mA$			(-)1.0	V
Output Capacitance	$C_{ob}$	$V_{CB} = (-)6V, f = 1MHz$		2.7		pF
				(3.7)		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-)6			V
Noise Level	$V_{NO(ave)}$	$V_{CC} = (-)30V, I_C = (-)1mA, R_g = 56k\Omega, V_G = 77dB/1kHz$			40	mV
					35	mV
Noise Peak Level	$V_{NO(peak)}$	$V_{CC} = (-)30V, I_C = (-)1mA, R_g = 56k\Omega, V_G = 77dB/1kHz$			280	mV
					(200)	mV

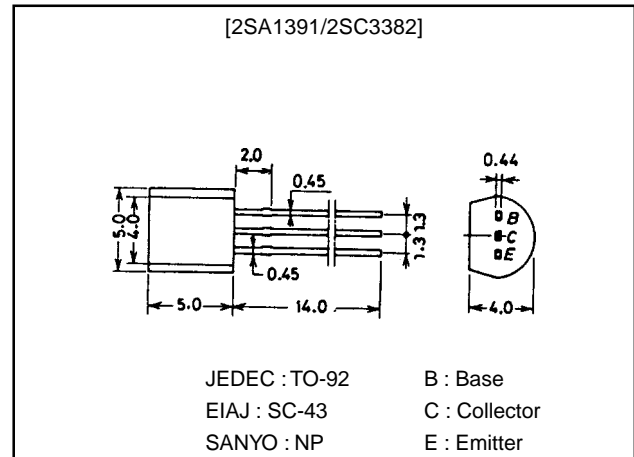
\* : 2SA1391/2SC3382 are classified by 1mA  $h_{FE}$  as follows :

100	R	200	140	S	280	200	T	400	280	U	560
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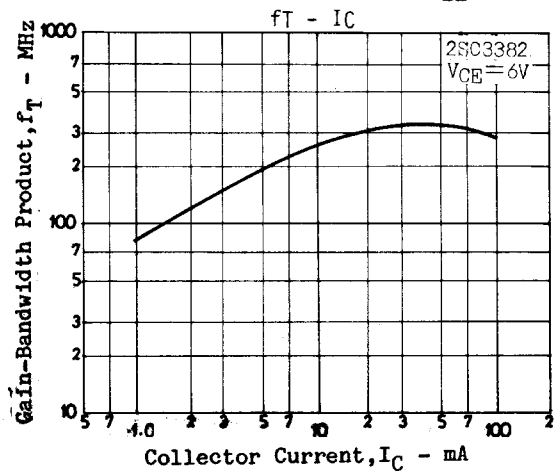
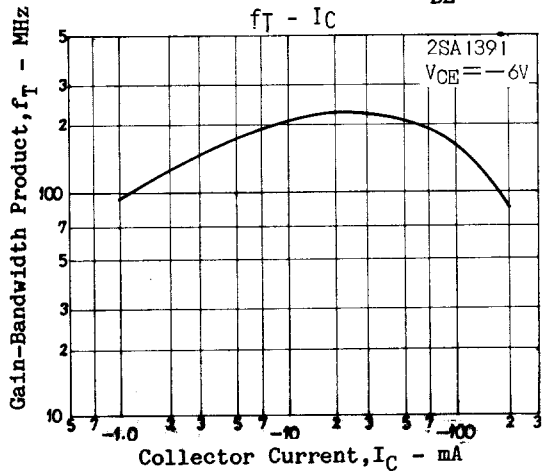
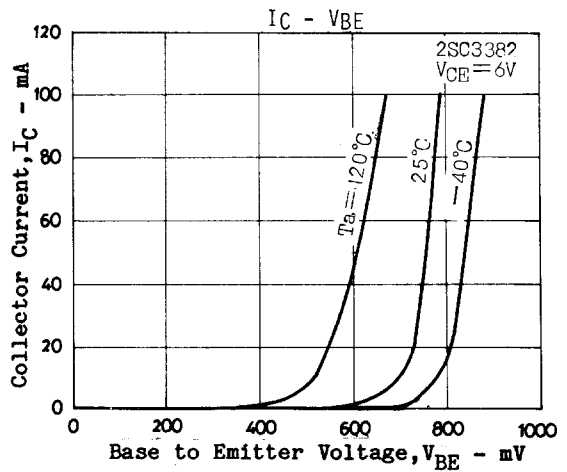
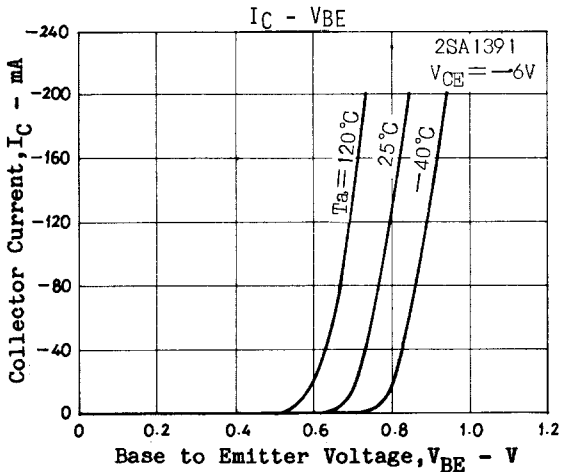
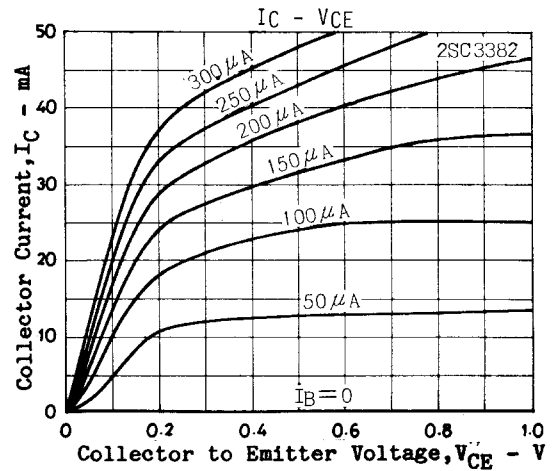
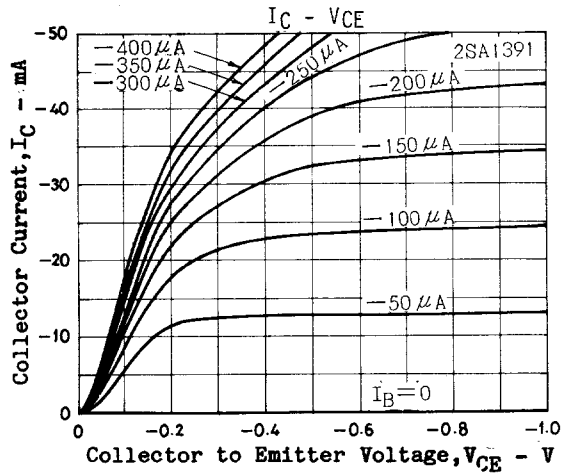
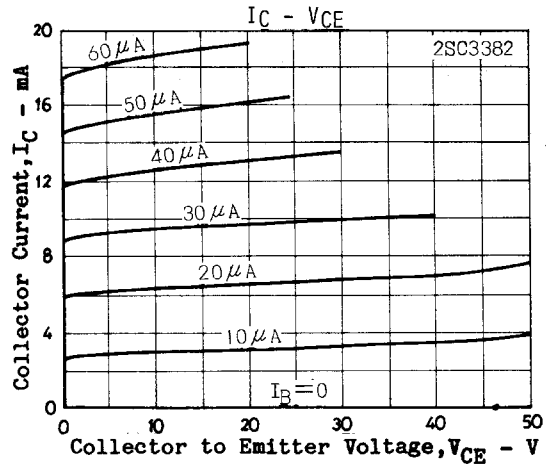
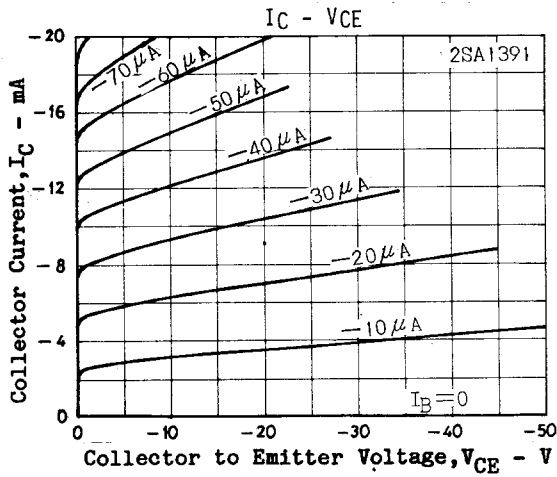
**Package Dimensions**

unit:mm

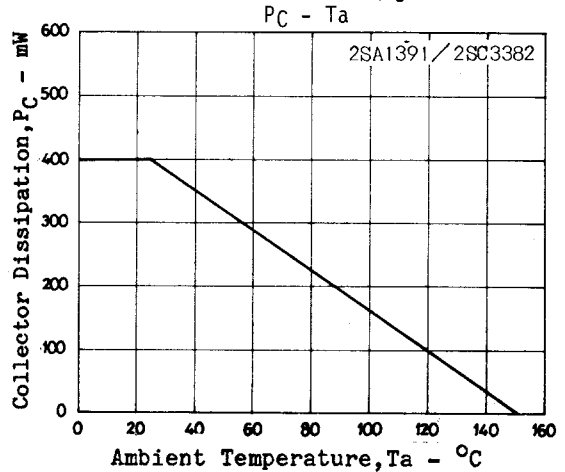
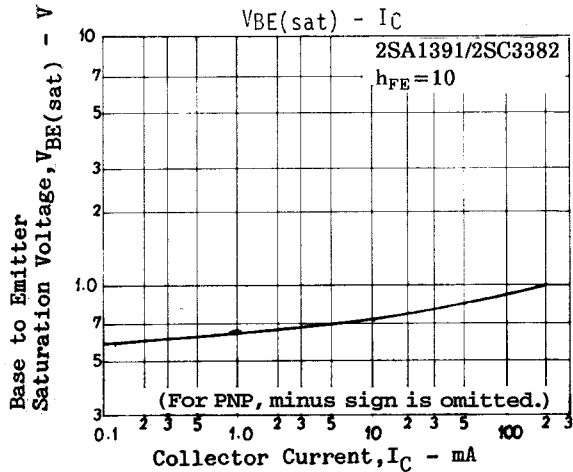
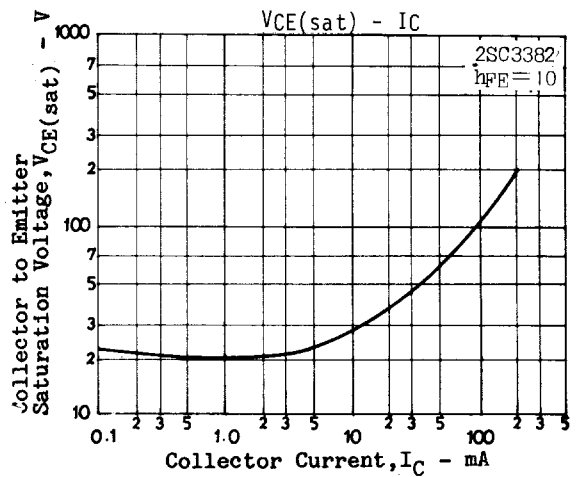
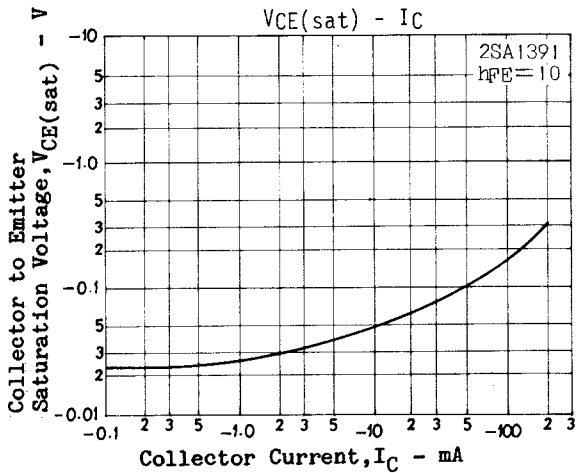
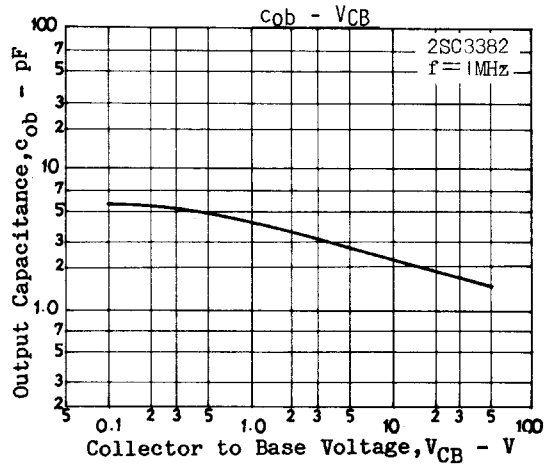
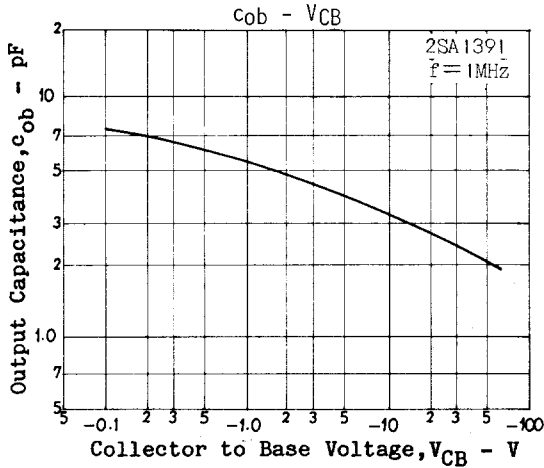
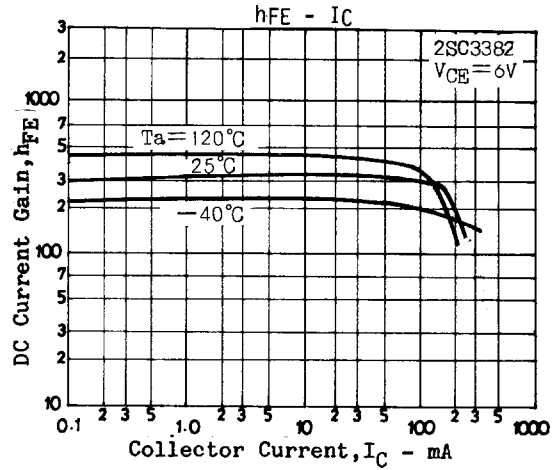
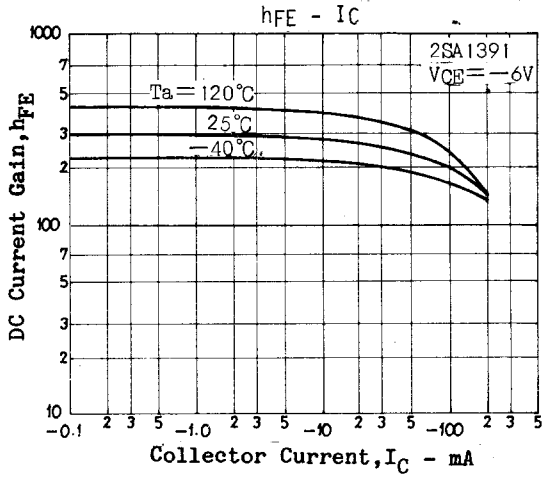
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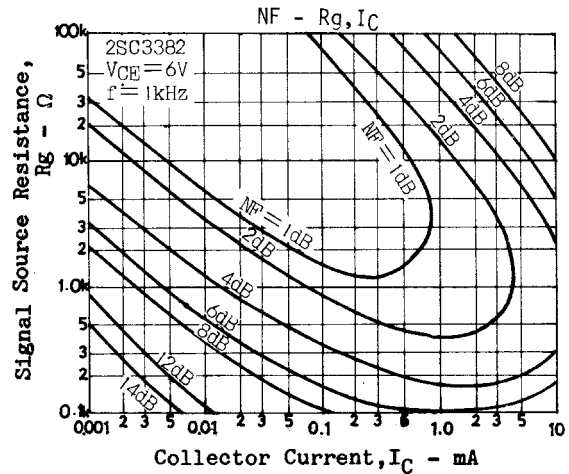
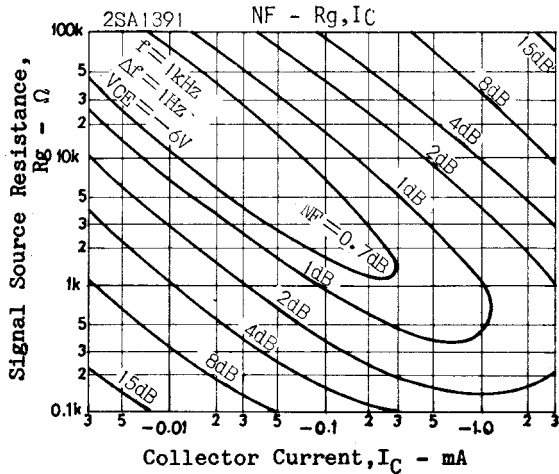
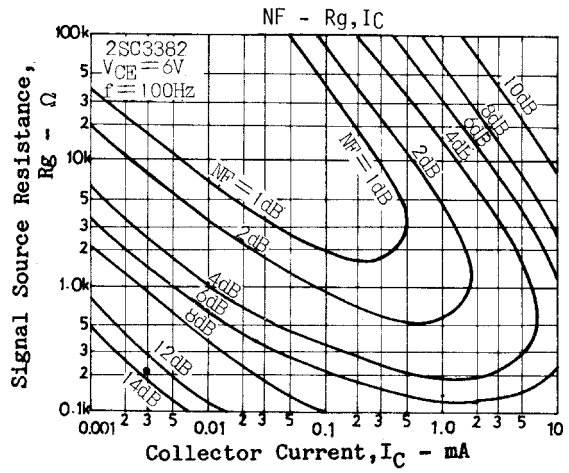
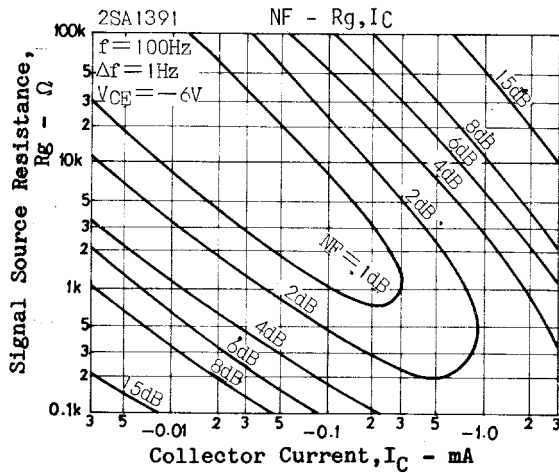
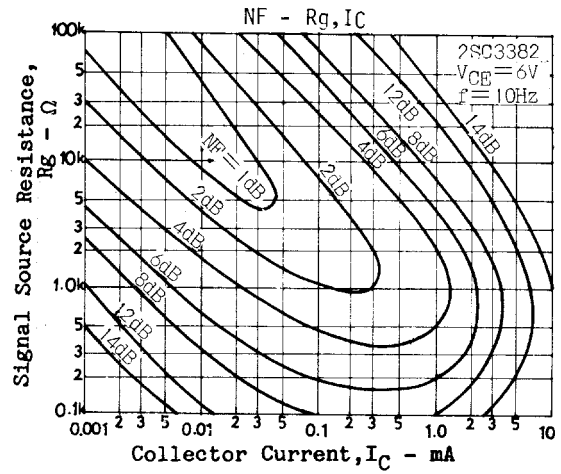
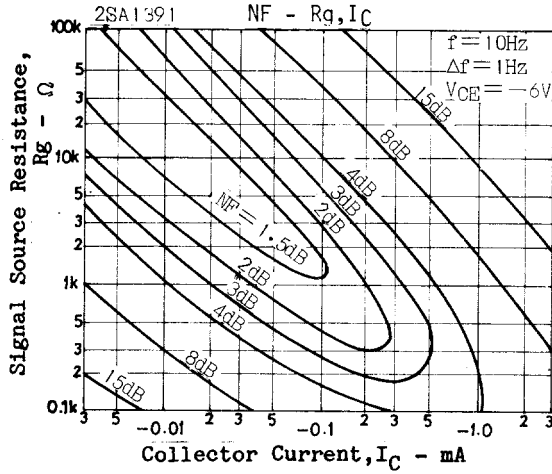
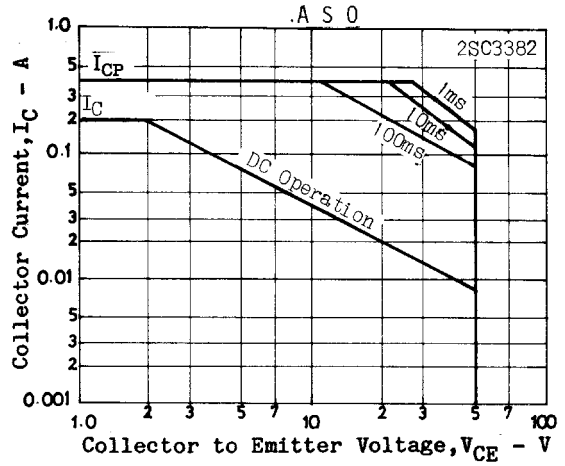
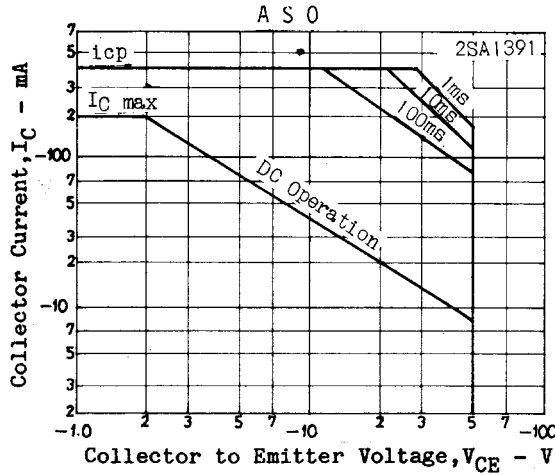
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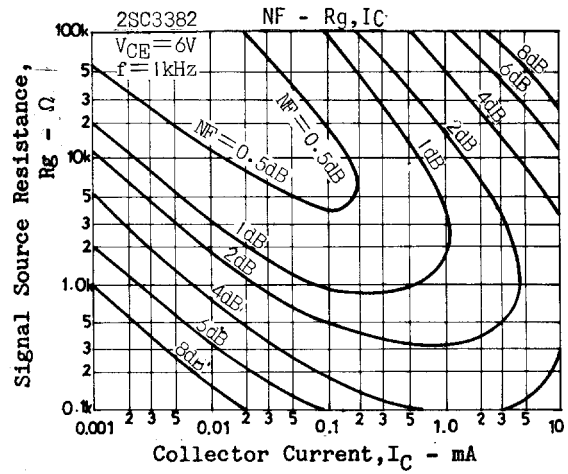
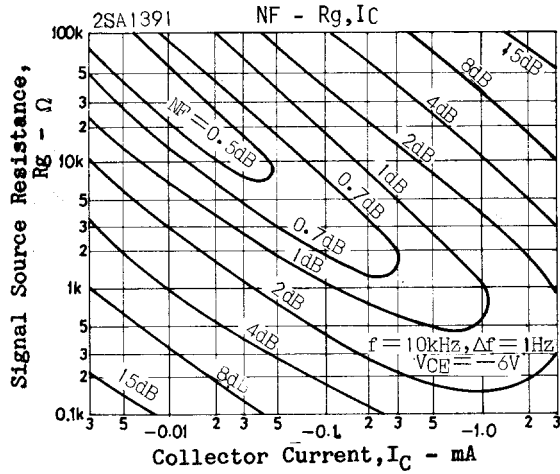
# 2SA1391/2SC3382



# 2SA1391/2SC3382



## 2SA1391/2SC3382



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